





Docket No.: M4065.0505/P505

(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Letters Patent of: Kristy A. Campbell et al.

Patent No.: 6,867,064

Issued: March 15, 2005

Certificate SEP 0 1 2005

of Correction

For: METHOD TO ALTER CHALCOGENIDE GLASS FOR IMPROVED SWITCHING

CHARACTERISTICS

REQUEST TO CORRECT A CERTIFICATE OF CORRECTION PURSUANT TO 37 CFR 1.322

Attention: Certificate of Correction Branch Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sir:

Upon reviewing the attached Certificate of Correction for the above-identified patent, Patentees noted a typographical error. The following correction, listed on the original Request for Correction (copy attached), is still in error.

At page 7, column 2, "Yoji Kowamoto et al." reference, "Ionic Conduction in As₂S₃-Ag₂S,GeS₅GeS-Ag₂S and P₂S₅-Ag₂S Glasses," Journal of Non-Crystalline Solids 20 (1976), pgs. 393-404." should read: --Yoji Kawamoto et al. -"Ionic Conduction in As₂S₃-Ag₂S,GeS₂GeS-Ag₂S and P₂S₅-Ag₂S Glasses," Journal of Non-Crystalline Solids 20 (1976), pgs. 393-404.

Transmitted herewith is a proposed Certificate of Correction effecting such amendment. Patentees respectfully solicit the granting of the requested corrected Certificate of Correction and believe no fee is involved.

Patent No.: 6,867,064 Docket No.: M4065.0505/P505

Dated: August 29, 2005

Respectfully submitted,

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UNITED STATES PATENT AND TRADEMARK OFFICE CERTIFICATE OF CORRECTION

PATENT NO. : 6,867,064 B2 Page 1 of 1

DATED : March 15, 2005 INVENTOR(S) : Kristy A. Campbell et al.

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Title page,

Item [56], References Cited, U.S. PATENT DOCUMENTS, "5,335,519 A 8/1994 Bernie" should read -- 5,335,219 8/1994 Ovshinsky et al. --

OTHER PUBLICATIONS, "El Bouchairi, B.; Bernede, J.C.; reference, "El Bouchairi, B.; Bernede, J.C.; Burgaud, P., Properties of Ag2-xSel+x/n-Si diodes, Thin Solid Films 110 (1983) 107-113." should read -- El Bourchairi, B.; Bernede, J.C.; Burgaud, P., Properties of Ag2-xSel+x/n-Si diodes, Thin Solid Films 110 (1983) 107-113. -- "Feng, X.; Bresser," reference "Feng, X.; Bresser, W.J.; Boolchand, P., Directed evidence for stiffness threshold in Chalcogenide glasses, Phys, Rev. Lett. 78 (1997) 4422-4425." should read -- Feng, X.; Bresser, W.J.; Boolchand, P., Direct evidence for stiffness threshold in chalcogenide glasses, Phys. Rev. Lett. 78 (1997) 4422-4425. -- "Hosokawa, S., reference, "Hosokawa, S., Atomic and electronic structures of glassy GexSel-x around the stiffness threshold composition, J. Optoelectroncis and Advanced Materials 3 (2001) 199-214." should read -- Hosokawa, S., Atomic and electronic structures of glassy GexSel-x around the stiffness threshold composition, J. Optoelectronics and Advanced Materials 3 (2001) 199-214. -- "Mitokova, M.; Wang, Y Boolchand, P.," reference Dual chemical role of Ag as an additive in chalcenide glasses Phys. Rev. Lett. 83 (1999) 3848-3851." should read

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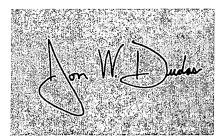
"Yoji Kowamoto et al." reference, "Ionic Conduction in As₂S₃-Ag₂S,GeS₂Ges-Ag₂S and P₂S₅-Ag₂S Glasses," Journal of Non-Crystalline Solids 20 (1976), pgs. 393-404." should read -- Yoji Kawamoto et al.,-"Ionic Conduction in As₂S₃-Ag₂S,GeS₅ GeS-Ag₂S and P₂S₅-Ag₂S Glasses," Journal of Non-Crystalline Solids 20 (1976), pgs.

GeS-Ag₂S and P_2S_5 -Ag₂S Glasses," Journal of Non-Crystalline Solids 20 (1976), pgs 393-404. --



Signed and Sealed this

Twenty-eighth Day of June, 2005



JON W. DUDAS Director of the United States Patent and Trademark Office

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(Also Form PTO-1050)

UNITED STATES PATENT AND TRADEMARK OFFICE CERTIFICATE OF CORRECTION

Page _1_ of _1_

PATENT NO.

6,867,064

APPLICATION NO.

10/075,390

ISSUE DATE

March 15, 2005

INVENTOR(S)

Kristy A. Campbell et al.

It is certified that an error appears or errors appear in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

In OTHER PUBLICATIONS:

At page 7, column 2, "Yoji Kowamoto et al." reference, "Ionic Conduction in $As_2S_3-Ag_2S$, $GeS_5GeS-Ag_2S$ and $P_2S_5-Ag_2S$ Glasses," Journal of Non-Crystalline Solids 20 (1976), pgs. 393-404." should read: --Yoji Kawamoto et al. -"Ionic Conduction in $As_2S_3-Ag_2S$, $GeS_2GeS-Ag_2S$ and $P_2S_5-Ag_2S$ Glasses," Journal of Non-Crystalline Solids 20 (1976), pgs. 393-404.

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